

A new electrochemical synthesis route for a BiOI electrode and its conversion to a highly efficient porous BiVO₄ photoanode for solar water oxidation†

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A new electrodeposition condition utilizing *p*-benzoquinone reduction was developed to produce BiOI electrodes composed of extremely thin 2D BiOI crystals. These electrodes served as precursors to form porous BiVO₄ electrodes *via* mild chemical and thermal treatments. The resulting porous BiVO₄ electrodes showed outstanding photoelectrochemical performance for sulfite oxidation reaching 1.25 mA cm⁻² at 0.5 V *vs.* RHE in 0.1 M potassium phosphate buffer (pH 7) containing 0.1 M sodium sulfite. When a *ca.* 100 nm thick FeOOH layer was deposited on the surface of BiVO₄ as an oxygen evolution catalyst, the kinetics of water oxidation was improved to the level of sulfite oxidation and the maximum power point for solar water oxidation was achieved at a bias as low as 0.55 V *vs.* RHE with a photocurrent density of 1.17 mA cm⁻². The remarkable solar water oxidation performance achieved by the porous BiVO₄-FeOOH system strongly encourages further morphological and compositional optimizations of the BiVO₄-based photoanode systems to realize highly efficient and practical solar water oxidation.

Bismuth vanadate (BiVO₄), an n-type semiconductor, has been recently identified as a promising photoanode for use in a photoelectrochemical water splitting cell.^{1–21} It has a direct bandgap of 2.4 eV and an appropriate valence band position for O₂ evolution. In addition, the conduction band of BiVO₄ is located very near the H₂ evolution potential, allowing the photocurrent onset to occur very near 0.0 V *vs.* RHE. This feature enables BiVO₄ to have an earlier photocurrent onset and generate much higher photocurrent in the low bias region than other photoanodes having a smaller bandgap but a more positive conduction band edge. When a photoanode is coupled with a photocathode in a photoelectrochemical diode assembly, an early photocurrent onset and a high fill factor are critical for achieving a high overall operating current and, therefore, a high solar-to-hydrogen conversion efficiency.²²

Recently, the enhancement of the photocurrent of BiVO₄ photoanodes achieved by composition tuning and pairing with various oxygen evolution catalysts (OECs) has been reported.^{5,7,8,10–20} However, most of these studies dealt with BiVO₄ photoanodes having relatively low surface areas. Therefore, one straightforward way to further improve the performance of BiVO₄ would be the introduction of high porosity to the electrode, which will increase the volume of the depletion layer and reduce electron–hole recombination. In this study, we developed a new electrochemical synthesis route to produce BiOI electrodes by exploiting the reduction of *p*-benzoquinone, the advantage of which will be elaborated below. The resulting BiOI electrodes were used as precursors to form highly porous BiVO₄ electrodes by mild chemical and heat treatments. The porous BiVO₄ electrode when combined with FeOOH as an oxygen evolution catalyst showed outstanding performance for solar water

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† Electronic supplementary information (ESI) available: Detailed experimental procedures, XRD patterns of BiOI and BiVO₄, UV-vis spectra of BiVO₄ and BiVO₄/FeOOH, Mott–Schottky plots of BiVO₄, and a scheme showing how to determine P_{\max} and fill factor for a solar water oxidation half reaction when a three electrode system is used. See DOI: 10.1039/c2ee22608a

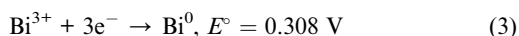
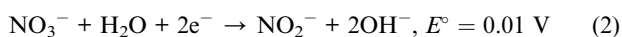
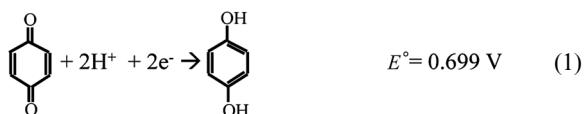
Broader context

Among various oxide electrodes studied as photoanodes for solar water oxidation, BiVO₄ has shown a possibility of efficiently generating a photocurrent in the low bias region (*i.e.*, $E < 0.8$ V *vs.* RHE) as its flatband potential is located very near to the H₂ evolution potential (0.0 V *vs.* RHE). This feature is critical in achieving a high overall operating current in a p–n photoelectrochemical diode assembly. To fully exploit this advantage, a new synthesis strategy to form porous BiVO₄ electrodes that can minimize electron–hole recombination was developed. The resulting porous BiVO₄ electrode combined with an FeOOH oxygen evolution catalyst showed remarkable photoelectrochemical water oxidation performance in terms of photocurrent onset, the position of the maximum power points, fill factor, and the level of current density achieved in the low bias region. This result shows great promise to achieve efficient and practical solar water oxidation using only non-precious elements *via* simple synthesis procedures.

oxidation, achieving the maximum power point at a bias as low as 0.55 V vs. RHE with a photocurrent density of 1.17 mA cm⁻², which makes this system one of the most promising photoanodes for solar water oxidation.

The synthesis procedure used in this study is summarized in Fig. 1. The first step was the electrodeposition of BiOI electrodes by the reduction of *p*-benzoquinone to hydroquinone (eqn (1)) (Fig. 1a).²³ The plating solution was prepared by dissolving 20–40 mM Bi(NO₃)₃ in a solution of 400 mM KI at pH 1.75 adjusted by HNO₃. I⁻ serves as a complexing agent to stabilize Bi³⁺ as [BiI₄]⁻, which otherwise is not soluble in the aqueous plating medium. 50 mM *p*-benzoquinone was added to this solution. When the *p*-benzoquinone was reduced to hydroquinone at the working electrode (WE) at -0.1 V vs. Ag/AgCl (4 M KCl), it consumes H⁺ ions and the resulting local pH increase on the WE triggers the precipitation of crystalline BiOI on the WE, which was confirmed by X-ray diffraction (ESI, Fig. S1†). More detailed experimental procedures can be found in the ESI.†

Previously, electrodeposition utilizing local pH increase on the WE has typically used the reduction of nitrate (eqn (2)).^{23,24} However, many compounds that contain metal ions having a relatively positive reduction potential such as BiOI containing Bi³⁺ could not be electrochemically produced using nitrate reduction because metal ions present in the plating solution are reduced to metal before nitrate reduction occurs (e.g., Bi³⁺ to Bi⁰, eqn (3)).²² In this study, we exploited the electrochemical reduction of *p*-benzoquinone, which has a much more positive reduction potential (eqn (1)) than Bi³⁺, to make the electrodeposition of BiOI possible. There has been one study on using *p*-benzoquinone reduction for the deposition of a biopolymer, chitosan,²⁵ but this is the first demonstration of utilizing benzoquinone reduction for inorganic materials synthesis, which will significantly expand the scope of electrochemical materials synthesis.



The second step was the conversion of BiOI to BiVO₄, which was achieved by adding a 30% NH₄OH solution containing 100 mM V₂O₅ on the BiOI surface and annealing in air at 520 °C for 6 h

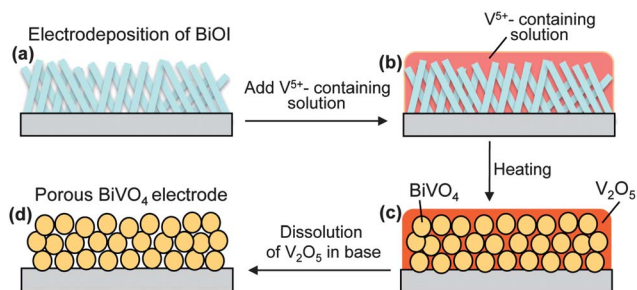


Fig. 1 Schematic representation of the procedures used to prepare porous BiVO₄ electrodes.

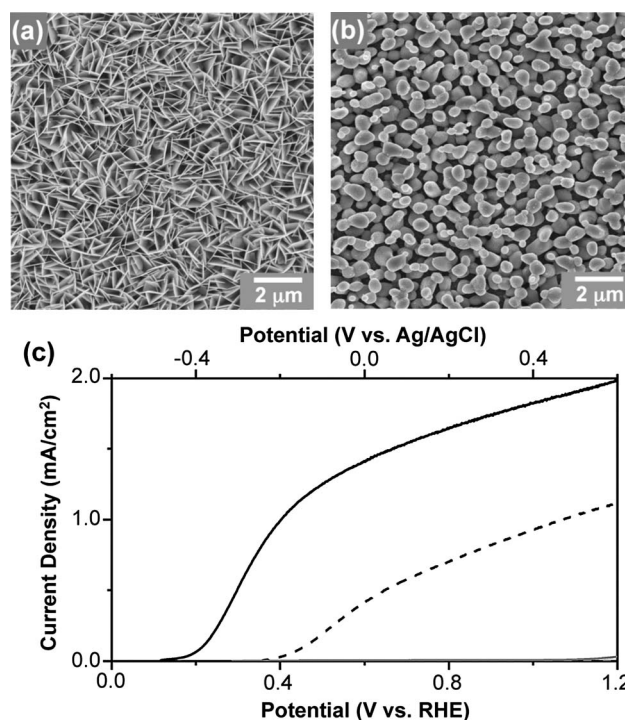


Fig. 2 SEM images of (a) BiOI and (b) BiVO₄ electrodes; (c) photocurrent density–potential curve of BiVO₄ electrodes in 0.1 M phosphate buffer (pH 7) before (---) and after (—) adding 0.1 M sulfite (AM 1.5G, 100 mW cm⁻² illumination). Dark currents are shown as gray lines.

(Fig. 1b and c). The annealing procedure resulted in the decomposition of BiOI into Bi₂O₃ and I₂, which sublimates. Then Bi₂O₃ reacted with V₂O₅ to form BiVO₄. Due to the excess amount of V⁵⁺ ions in the solution added, the resulting film contained amorphous V₂O₅ as an impurity phase, which was removed by soaking the electrode in a 1 M NaOH solution for 20 min while stirring (Fig. 1d). After the soaking process, energy dispersive spectroscopy confirmed that the Bi : V ratio of the electrode is 1 : 1 and no iodide is present in the film. XRD shows peaks from only the BiVO₄ phase having a monoclinic scheelite structure (JCPDS# 14-0688), confirming the absence of other crystalline impurity phases (ESI, Fig. S1†).

The SEM images of BiOI and BiVO₄ are shown in Fig. 2a and b, which demonstrate the advantage of producing BiVO₄ by the conversion of the electrochemically produced BiOI electrode. The BiOI electrode is composed of extremely thin two-dimensional (2D) plate-like crystals, which reflects the atomic level crystal structure of BiOI composed of 2D BiOI layers. During thermal annealing procedure, each 2D plate of BiOI was converted and contracted to a round particle of BiVO₄ having a 3D crystal structure, creating sub-micron scale voids between the particles. The discrete 2D plate morphologies of BiOI crystals with ample space between them appear to effectively limit the grain growth and the final grain size of BiVO₄ particles, resulting in the formation of porous BiVO₄ electrodes.

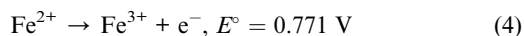
The photocurrent density–potential curve of BiVO₄ electrodes was measured under AM 1.5G (100 mW cm⁻²) illumination in 0.1 M potassium phosphate buffer (pH 7) (Fig. 2c). The BiVO₄ electrode produced an anodic photocurrent confirming the n-type nature of BiVO₄. However, the amount of the photocurrent generated for water oxidation was not impressive and also the photocurrent onset potential (0.35 V vs. RHE) was shifted considerably in the positive

direction from its flatband potential determined from the Mott–Schottky plots (*ca.* -0.05 V *vs.* RHE) (ESI, Fig. S2†). In order to determine whether the poor catalytic nature of the BiVO_4 surface for O_2 evolution serves as a limiting factor for photocurrent generation, 0.1 M sodium sulfite was added to the electrolyte. Oxidation of sulfite ($\text{SO}_3^{2-}/\text{SO}_3^-$, $E^\circ = 0.73$ V *vs.* NHE; $\text{SO}_3^{2-}/\text{S}_2\text{O}_6^{2-}$, $E^\circ = 0.026$ V *vs.* NHE), is thermodynamically and kinetically much more favourable than water oxidation.²⁶ Therefore, surface recombination losses due to slow interfacial hole transfer kinetics can be assumed negligible for photo-oxidation of sulfite. Indeed, when sulfite was present in the electrolyte, a remarkable increase in the photocurrent was observed, reaching 1.25 mA cm^{-2} at 0.5 V *vs.* RHE. This result clearly indicated that the slow interfacial kinetics for O_2 evolution played a role in suppressing the photocurrent of BiVO_4 for water oxidation.

The photocurrent generated by the porous BiVO_4 for sulfite oxidation is much higher than that by the recently reported non-porous BiVO_4 electrode, which was prepared by annealing electrochemically produced amorphous Bi–V–O films.¹⁹ For example, the non-porous BiVO_4 electrode generated a photocurrent of 0.73 mA cm^{-2} at 0.5 V *vs.* RHE when the photocurrent–potential characteristics were obtained using the identical condition. However, the porous BiVO_4 electrode generated a photocurrent of 1.25 mA cm^{-2} at 0.5 V *vs.* RHE, indicating *ca.* 70% photocurrent improvement. The flatband potential values for the non-porous and porous BiVO_4 electrodes obtained from Mott–Schottky plots (ESI, Fig. S2†) are comparable,¹⁹ suggesting that the observed performance difference is not due to the difference in carrier density or flatband potential but mainly due to the increase in the surface area, thereby increasing the volume of the depletion layer and reducing electron–hole recombination.

The early photocurrent onset (0.21 V *vs.* RHE) and remarkably high photocurrent generated by the porous BiVO_4 electrode in the low bias region for sulfite oxidation are very encouraging because they suggest that a similar level of photocurrent may be achieved for water oxidation if an appropriate oxygen evolution catalyst (OEC) is placed on the BiVO_4 surface. To probe this possibility, FeOOH that was recently identified as a good OEC to couple with BiVO_4 was conformally coated on the BiVO_4 electrode by photodeposition.¹⁹

Photodeposition of FeOOH was carried out by back-side illumination of BiVO_4 electrodes with an intensity of 1.6 mW cm^{-2} for 1 h in a 0.1 M FeCl_2 (pH 4) solution while stirring. The photodeposition is based on utilizing photogenerated holes in BiVO_4 to oxidize Fe(II) ions to Fe(III) ions (eqn (4)).^{27,28} Fe(III) ions are insoluble in an aqueous medium ($[\text{Fe}^{3+}] \sim 10^{-7}$ at pH = 4.1) and precipitate out as FeOOH on the BiVO_4 film (eqn (5)).^{27,28} A constant potential of $+0.27$ V *vs.* Ag/AgCl (4 M KCl) was applied during photodeposition to increase the photodeposition rate. (This potential is not enough to electrodeposit FeOOH.)



Since photodeposition utilizes photogenerated holes in BiVO_4 to oxidize Fe(II) to Fe(III), FeOOH by photodeposition was formed only on the BiVO_4 surface. Therefore, in order to ensure that any bare FTO substrate exposed between the BiVO_4 particles was covered by FeOOH, additional electrodeposition of FeOOH was carried out by applying $+1.2$ V *vs.* Ag/AgCl (4 M KCl) for 10 min in the same solution

after photodeposition. Exposure of the bare FTO surface to the electrolyte may leak photoexcited electrons to the electrolyte before they reach the counter electrode, decreasing the overall photocurrent. Both the photodeposition time and electrodeposition time of FeOOH reported here were optimized to maximize the photocurrent generated by $\text{BiVO}_4/\text{FeOOH}$ electrodes for O_2 evolution.

Top and side view SEM images of the FeOOH layers deposited on BiVO_4 electrodes are shown in Fig. 3a and b. The top view SEM image shows that the catalyst uniformly covers the surface of the BiVO_4 electrode while maintaining the porosity between the BiVO_4 particles. The side view SEM image clearly shows the conformal nature of the *ca.* 100 nm thick FeOOH coating on individual BiVO_4 particles.

The photocurrent for water oxidation in 0.1 M potassium phosphate buffer generated by a $\text{BiVO}_4/\text{FeOOH}$ photoanode is shown in Fig. 3c. The presence of FeOOH greatly improved the photocurrent for water oxidation such that it became very close to the level of photocurrent generated for sulfite oxidation by the BiVO_4 electrode (Fig. 2c). However, the photocurrent for water oxidation by the $\text{BiVO}_4/\text{FeOOH}$ photoanode is still lower than the photocurrent for sulfite oxidation by the BiVO_4 photoanode, indicating that a portion of the holes that reach the surface of the $\text{BiVO}_4/\text{FeOOH}$ photoanode were lost by surface recombination during water oxidation.

Due to the early photocurrent onset (0.21 V *vs.* RHE) and an outstanding fill factor of the photocurrent profile, the maximum power point (P_{max}) for water oxidation was achieved at 0.55 V *vs.* RHE with a photocurrent density of 1.17 mA cm^{-2} . (See ESI,

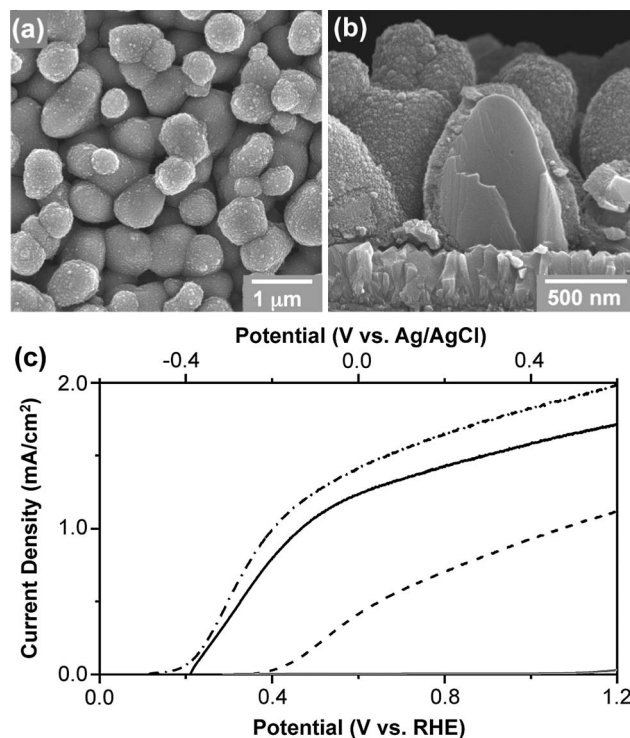


Fig. 3 (a) Top view and (b) side view SEM images of $\text{BiVO}_4/\text{FeOOH}$ photoanode; (c) photocurrent density–potential curve of $\text{BiVO}_4/\text{FeOOH}$ photoanode in 0.1 M phosphate buffer (pH 7) (—). Dark current is shown as a gray line. For easy comparison, photocurrent density–potential curves of bare BiVO_4 photoanode for water oxidation (---) and sulfite oxidation (· · ·) shown in Fig. 2c are also included (AM 1.5G, 100 mW cm^{-2} illumination).

Fig. S3† for the determination of P_{\max} and fill factor for a solar water oxidation half reaction when a three electrode system is used.)²² The fact that the P_{\max} is achieved at a bias as low as 0.55 V vs. RHE and the photocurrent density obtained at 0.55 V vs. RHE is as high as 1.17 mA cm⁻² makes the porous BiVO₄/FeOOH electrode one of the best oxide-based photoanode systems reported to date. The outstanding performance of BiVO₄/FeOOH demonstrated in this study was possible owing to the combination of the very negative flatband potential of BiVO₄, the porous structure of BiVO₄ minimizing electron-hole recombination, and FeOOH being able to improve the water oxidation kinetics considerably.

The performance shown in Fig. 3c is the average performance of our BiVO₄/FeOOH systems, which is significantly improved from the average performance of the previously reported non-porous BiVO₄/FeOOH electrodes.¹⁹ For example, photocurrent densities achieved at 0.55 V vs. RHE in the photocurrent-potential characteristics are 1.17 mA cm⁻² and 0.82 mA cm⁻² for an average porous BiVO₄/FeOOH and an average non-porous BiVO₄/FeOOH, respectively. However, the performance difference observed for water oxidation between porous and non-porous BiVO₄ electrodes was less than the performance difference observed for sulfite oxidation.¹⁹ This is because unlike sulfite oxidation, the increase in electron-hole separation achieved by the porous structure is not fully utilized to increase the photocurrent for water oxidation in the porous BiVO₄/FeOOH electrode. Improving the quality of the BiVO₄/FeOOH junction and identifying a more efficient OEC that can better interface with the BiVO₄ surface are under investigation in order to completely suppress surface recombination losses and maximize photocurrent for water oxidation.

When the BiVO₄/FeOOH electrode was used for sulfite oxidation and was compared with the performance of the bare BiVO₄ for sulfite oxidation, no improvement in the photocurrent was observed. This indicates that although FeOOH itself is a semiconductor having a bandgap of ca. 2.1 eV (ESI Fig. S2†),^{19,27} it does not play a role in enhancing photon absorption or electron-hole separation in the case of sulfite oxidation. Therefore, the enhancement in the photocurrent for water oxidation achieved by BiVO₄/FeOOH is due to FeOOH mainly serving as an oxygen evolution catalyst.

The stability of the BiVO₄/FeOOH photoanode was tested by monitoring the photocurrent density change over time while applying a constant potential of 0.5 V vs. RHE. Fig. 4(a) shows that the steady state photocurrent of ca. 0.9 mA cm⁻² was maintained for six hours without noticeable decay. The fluctuation of the photocurrent observed in the plot is due to O₂ bubbles collected on the electrode surface interfering with photocurrent generation and also due to our attempts to manually remove the O₂ bubbles by shaking the electrode or the electrolyte, which also resulted in a slight change in the distance between the electrode and the light source (or the volume of electrolyte between them). The inset of Fig. 4(a) shows that when BiVO₄ is not coupled with FeOOH, the initial photocurrent decays quickly to a significantly lower steady state photocurrent due to the poor catalytic nature of BiVO₄ for water oxidation.

In order to confirm that the photocurrent generated by BiVO₄/FeOOH at 0.5 V vs. RHE using 100 mW cm⁻² AM 1.5G illumination was truly associated with water oxidation, O₂ detection measurement was carried out during photoelectrolysis of water. The photocurrent-to-O₂ conversion efficiency was calculated by comparing the amount of O₂ calculated from the photocurrent assuming 100% Faradaic efficiency and the actual amount of O₂

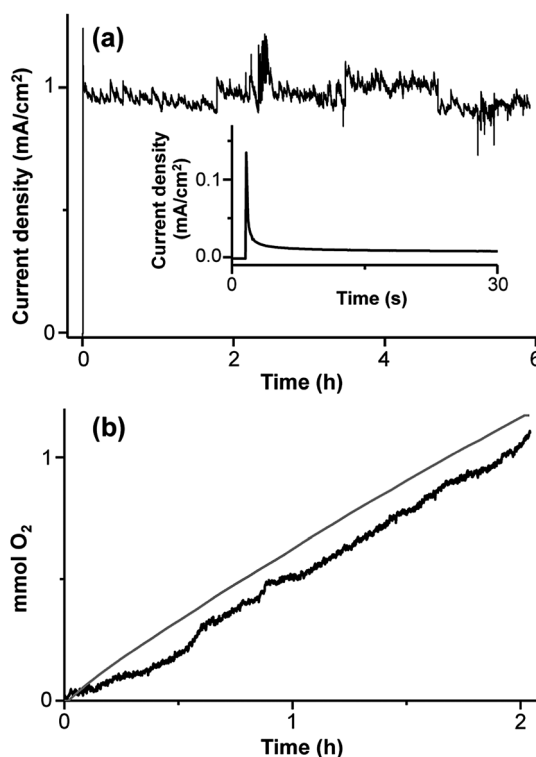


Fig. 4 (a) Photocurrent of BiVO₄ (inset) and BiVO₄/FeOOH photoanode measured at 0.5 V vs. RHE in 0.1 M phosphate buffer (pH 7); (b) the amount of O₂ calculated from the photocurrent assuming 100% Faradaic conversion efficiency (gray line) and the amount of O₂ actually detected (black line) when BiVO₄/FeOOH photoelectrode operates at 0.5 V vs. RHE in 0.1 M phosphate buffer (pH 7). For both (a) and (b) AM 1.5G, 100 mW cm⁻² illumination was used.

produced during photoelectrolysis, which was measured by a fluorescence-based O₂ sensor. The result shows that 95% of photocurrent was used for O₂ production (Fig. 4b). The remaining 5% of photocurrent may be due to experimental errors associated with the precision of the O₂ sensor (ca. ±5%) or the photocurrent associated with photocorrosion occurring at the pinholes where FeOOH is not completely covering the BiVO₄ surface. No visible sign of photocorrosion in our BiVO₄/FeOOH electrodes was observed after several hours of photoelectrolysis operation, but photocorrosion of bare BiVO₄ used for water oxidation without a good OEC has been well noted in the literature.^{1,6,19}

In summary, we have developed a new cathodic electrodeposition condition to prepare crystalline BiOI electrodes using *p*-benzoquinone reduction. The polycrystalline BiOI electrode composed of extremely thin 2D plates allowed for the preparation of porous BiVO₄ photoanodes using a simple chemical and thermal treatment. The resulting porous BiVO₄ electrodes showed remarkable photoelectrochemical performance for sulfite oxidation and also for water oxidation when combined with FeOOH OEC. For solar water oxidation, the BiVO₄/FeOOH photoanode achieved the P_{\max} point at 0.55 V vs. RHE with a photocurrent density of 1.17 mA cm⁻². The outstanding and stable solar water oxidation performance achieved by the BiVO₄/FeOOH system composed of only non-precious elements prepared by simple synthesis procedures warrants further optimization studies on morphologies and compositions of the BiVO₄-based photoanodes.

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